

BC847C-13-F Datasheet

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DiGi Electronics Part Number	BC847C-13-F-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	BC847C-13-F
Description	TRANS NPN 45V 0.1A SOT23-3
Detailed Description	Bipolar (BJT) Transistor NPN 45 V 100 mA 300MHz 3 10 mW Surface Mount SOT-23-3

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC847C-13-F	Diodes Incorporated
Series:	Product Status:
-	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	600mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
15nA	200 @ 2mA, 5V
Power - Max:	Frequency - Transition:
310 mW	300MHz
Operating Temperature:	Mounting Type:
-65°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	SOT-23-3
Base Product Number:	
BC847	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	





BC846A-BC848C

NPN SMALL SIGNAL TRANSISTOR IN SOT23

Features

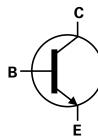
- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856–BC858
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under separate datasheet (<u>BC846AQ-BC848CQ</u>)

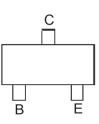
Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.008 grams (Approximate)



Top View





Top View

Pin-Out

Device Symbol

Ordering Information (Note 4)

Devi Nevel en	Destaurs	Mandalara		Pacl	king
Part Number	Package	Marking	Reel Size (inches)	Qty.	Carrier
BC846A-7-F	SOT23	K1Q	7	3,000	Reel
BC846B-7-F	SOT23	K1R	7	3,000	Reel
BC846B-13-F	SOT23	K1R	13	10,000	Reel
BC847A-7-F	SOT23	K1Q	7	3,000	Reel
BC847A-13-F	SOT23	K1Q	13	10,000	Reel
BC847B-7-F	SOT23	K1R	7	3,000	Reel
BC847B-13-F	SOT23	K1R	13	10,000	Reel
BC847C-7-F	SOT23	K1M	7	3,000	Reel
BC847C-13-F	SOT23	K1M	13	10,000	Reel
BC848A-7-F	SOT23	K1Q	7	3,000	Reel
BC848B-7-F	SOT23	K1R	7	3,000	Reel
BC848B-13-F	SOT23	K1R	13	10,000	Reel
BC848C-7-F	SOT23	K1M	7	3,000	Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

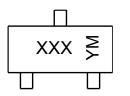
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



XXX = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: L = 2024) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2007	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	U	-	L	М	Ν	Р	R	S	Т	U	V	W
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	;	Symbol	Value	Unit
	BC846A/B		80	
Collector-Base Voltage	BC847A/B/C	Vсво	50	V
	BC848A/B/C		30	-
	BC846A/B		65	
Collector-Emitter Voltage	BC847A/B/C	VCEO	45	V
	BC848A/B/C		30	
Emitter-Base Voltage	BC846A/B BC847A/B/C	Vebo	6.0	V
	BC848A/B/C		5.0	-
Continuous Collector Current	·	lc	100	mA
Peak Collector Current		Ісм	200	mA
Peak Emitter Current		Іем	200	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Dower Dissinction	(Note 5)	D-	310	~\\/
Power Dissipation	(Note 6)	PD	350	mW
Thermal Desistance, Junction to Ambient	(Note 5)	D	403	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	357	C/VV
Thermal Resistance, Junction to Leads	(Note 7)	Rejl	350	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-65 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

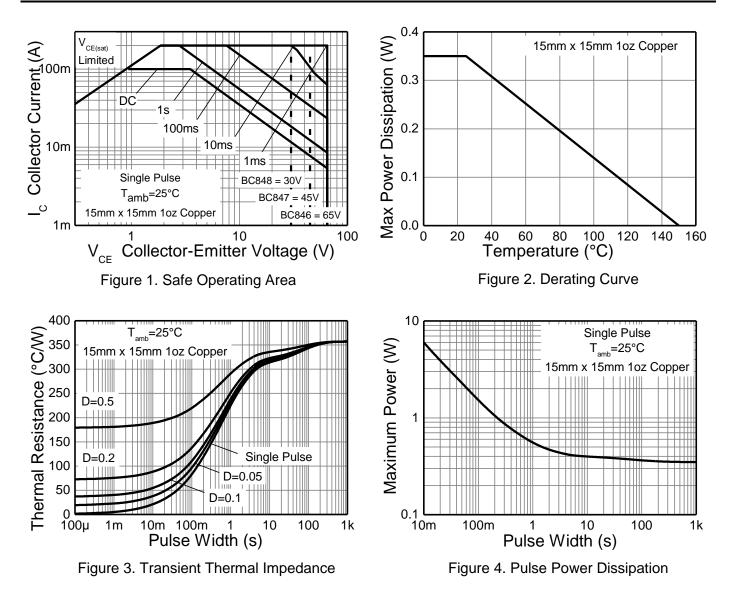
Notes: 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted on 15mm x 15mm 1oz copper.

Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Charac	cteristic		Symbol	Min	Тур	Max	Unit	Test Condition
		BC846A/B		80				
Collector-Base Breakdown Vo	oltage	BC847A/B/C	ВУсво	50		_	V	I _C = 10μΑ
		BC848A/B/C		30				
		BC846A/B		65				
Collector-Emitter Breakdown ' (Note 9)	Voltage	BC847A/B/C	BVCEO	45		_	V	Ic = 10mA
(Note 9)		BC848A/B/C		30				
Emitter-Base Breakdown Volt	age	BC846A/B BC847A/B/C	ВVево	6		_	V	I _E = 1μA
		BC848A/B/C		5				-
Collector Cutoff Current			Ісво		_	15	nA	Vcb = 30V
			юво			5	μΑ	V _{CB} = 30V, T _J = +150°C
BC846A/B Collector Emitter Cutoff Current BC847A/B/C		BC846A/B			15		$V_{CE} = 80V$	
		BC847A/B/C	ICES	—	—	15	nA	$V_{CE} = 50V$
		BC848A/B/C				15		Vce = 30V
Emitter Base Cutoff Current			IEBO		—	100	nA	$V_{EB} = 5V$
	BC846A/E	C847A/BC848A		_	200			
Small Signal Current Gain (Note 9)	BC846B/E	C847B/BC848B	hfe		330	_	—	
	BC847C/E	C848C			600			
Input Impedance (Note 9)	BC846A/B	BC846A/BC847A/BC848A BC846B/BC847B/BC848B			2.7			I _C = 2.0mA, V _{CE} = 5V f = 1.0kHz
	BC846B/B			—	4.5	_	kΩ	
	BC847C/BC848C		hie		8.7			
	BC846A/BC847A/BC848A				18		μS	
Output Admittance (Note 9)	BC846B/B	BC846B/BC847B/BC848B BC847C/BC848C		_	30	_		
,	BC847C/E				60		•	
	BC846A/B	C847A/BC848A			1.5 x 10 ⁻⁴			1
Reverse Voltage Transfer	BC846B/B	BC846B/BC847B/BC848B		_	2 x 10 ⁻⁴	_	_	
Ratio (Note 9)	BC847C/E	C848C	h _{re}		3 x 10 ⁻⁴			
	BC846A/B	C847A/BC848A		110	180	220		
DC Current Gain (Note 9)	BC846B/B	C847B/BC848B	hfe	200	290	450	_	Ic = 2.0mA, Vce = 5V
	BC847C/E	C848C		420	520	800		
					90	250		Ic = 10mA, I _B = 0.5mA
Collector-Emitter Saturation V	oltage (Note	9)	VCE(sat)	—	200	600	mV	$I_{C} = 100 \text{mA}, I_{B} = 5.0 \text{mA}$
				580	660	700		$I_{C} = 2mA$, $V_{CE} = 5V$
Base-Emitter Turn-On Voltage	e (Note 9)		V _{BE(on)}		_	770	mV	$I_{C} = 10 \text{mA}, V_{CE} = 5 \text{V}$
					700			$I_{C} = 10 \text{mA}, I_{B} = 0.5 \text{mA}$
Base-Emitter Saturation Volta	ige (Note 9)		VBE(sat)	—	900	—	mV	$I_{C} = 100 \text{mA}, I_{B} = 5 \text{mA}$
Output Capacitance			Cobo		3	_	pF	$V_{CB} = 10V, f = 1.0MHz$
Transition Frequency			fT	100	300	_	MHz	$V_{CE} = 5V$, $I_C = 10mA$ f = 100MHz
Noise Figure			NF		2	10	dB	$V_{CE} = 5V, I_C = 200\mu A$ Rs = 2k Ω , f = 1kHz Δ f = 200Hz

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

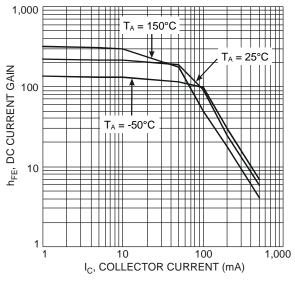
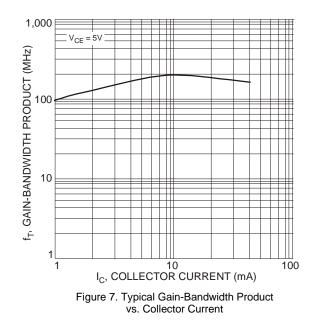
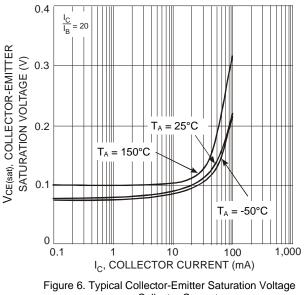


Figure 5. Typical DC Current Gain vs. Collector Current



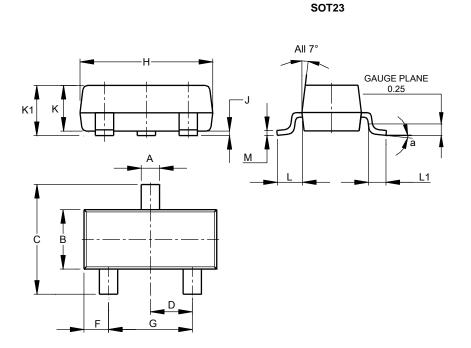


vs. Collector Current



Package Outline Dimensions

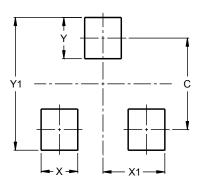
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Η	2.80	3.00	2.90
J	0.013	0.10	0.05
К	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
Μ	0.085	0.150	0.110
а	0°	8°	
All	Dimens	ions in	mm

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

SOT23



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